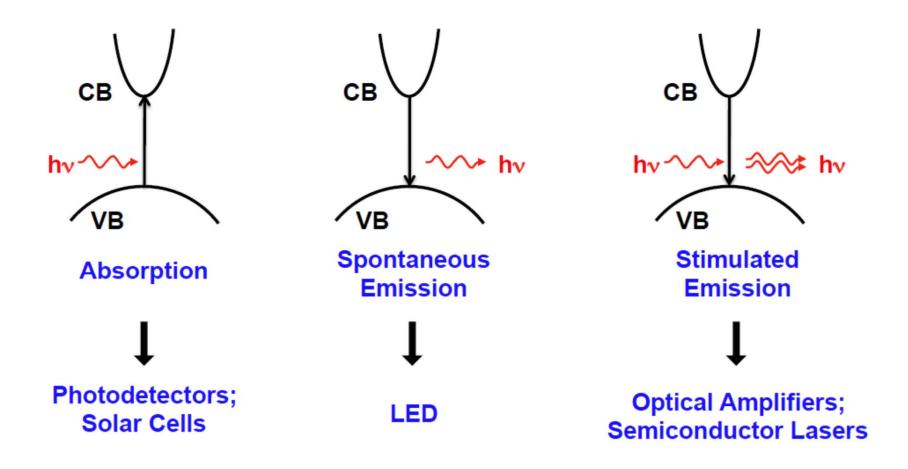


Band-to-Band Transition



Joint Density of States for Semiconductor

The electron states associated with optical transition r r r are related by conservation of mementum: $k_b \approx k_a \approx k$

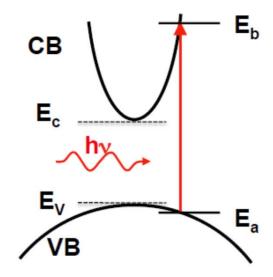
$$E_b = E_C + \frac{\bar{h}^2 k^2}{2m_e^*}$$
 $E_a = E_V - \frac{\bar{h}^2 k^2}{2m_h^*}$

$$E_b - E_a = (E_C - E_V) + \frac{\hbar^2 k^2}{2} \left(\frac{1}{m_e^*} + \frac{1}{m_h^*} \right)$$

$$h\omega = E_g + \frac{\hbar^2 k^2}{2m_r^*}$$

Joint density of states for the pair of electron states:

$$\rho_r(\hbar\omega - E_g) = \frac{1}{2\pi^2} \left(\frac{2m_r^*}{\hbar^2}\right)^{3/2} \sqrt{\hbar\omega - E_g}$$



CB completely full, VB completely empty, total upward transition at $\hbar\omega$:

$$R_{0}(\hbar\omega) = \frac{2}{V} \sum_{k} \left[\frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \delta(E_{b} - E_{a} - \hbar\omega) \right] = \frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \int \frac{2d\vec{k}}{(2\pi)^{3}} \delta(E_{g} + \frac{\hbar^{2}k^{2}}{2m_{r}^{*}} - \hbar\omega)$$

$$R_0(\hbar\omega) = \frac{2\pi}{\hbar} |H_{ba}|^2 \rho_r(\hbar\omega - E_g) \quad \text{unit: } [\frac{1}{m^3 s}]$$

Absorption coefficient

$$\alpha_{0}(\hbar\omega) = \frac{R(\hbar\omega)}{\text{photon flux}} = \frac{R(\hbar\omega)}{\frac{\varepsilon_{0}\varepsilon_{r}E_{0}^{2}}{2}\frac{c}{n_{r}}\frac{1}{\hbar\omega}} = \frac{R(\hbar\omega)}{\frac{\varepsilon_{0}n_{r}\omega^{2}A_{0}^{2}c}{2\hbar\omega}} \quad \text{unit: } \left[\frac{1}{m}\right]$$

$$\frac{\epsilon_0 \epsilon_r E_0}{2} \frac{c}{n_r} \frac{1}{\hbar \omega} = \frac{\epsilon_0 n_r \omega}{2\hbar \omega}$$

$$eA_0 \wedge =$$

$$H'_{ba} = -\frac{eA_0}{2m_0} \hat{e} \cdot \overrightarrow{P}_{cv}$$

$$\alpha_0(\hbar\omega) = C_0 \left| \hat{e} \cdot \vec{P}_{cv} \right|^2 \rho_r(\hbar\omega - E_g)$$

$$C_0 = \frac{\pi e^2}{n_r c \varepsilon_0 m_0^2 \omega} \approx 7 \times 10^9$$
 unit: $\left[\frac{m^2}{kg} \right]$

Typical Values of Optical Matrix Element

$$H_{ba}' = -\frac{eA_0}{2m_0} \hat{e} \cdot \overrightarrow{P}_{cv} = -e\overrightarrow{E} \cdot \overrightarrow{r}_{ba} = -ei\omega \frac{A_0}{2} \hat{e} \cdot \overrightarrow{r}_{ba} \Rightarrow \left| \overrightarrow{r}_{ba} \right| = \frac{\left| \overrightarrow{P}_{cv} \right|}{m_0 \omega}$$

The optical matrix element is often expressed in E_p :

$$\left| \hat{e} \cdot \overrightarrow{P}_{cv} \right|^2 = \frac{m_0}{6} E_p$$

Typical values of E_p (Table K.2 on p.709 of Chuang textbook)

GaAs:
$$E_p = 25.7 \text{ eV}$$
 The corresponding $|\vec{r}_{ba}| \sim 0.4 \text{ nm}$

AlAs:
$$E_p = 21.1 \text{ eV}$$

InAs:
$$E_p = 22.2 \text{ eV}$$

InP:
$$E_p = 20.7 \text{ eV}$$

GaP:
$$E_p = 22.2 \text{ eV}$$

Absorption Coefficient for GaAs

$$\alpha_0(\hbar\omega) = C_0 \left| \hat{e} \cdot \vec{P}_{cv} \right|^2 \rho_r(\hbar\omega - E_g)$$

$$nr := 3.5$$
 $\epsilon 0 := 8.854 \cdot 10^{-12} \frac{F}{m}$ $h_bar = 1.055 \times 10^{-34} \frac{m^2 \cdot kg}{s}$ $1eV = 1.6 \times 10^{-19} J$

Eg := 1.42eV
$$\omega := \frac{Eg}{h_bar}$$
 $\omega = 2.154 \times 10^{15} \frac{1}{s}$

$$C0 := \frac{\pi \cdot q^2}{m0^2 \cdot \omega \cdot \epsilon \cdot 0 \cdot c \cdot nr}$$

$$C0 = 4.842 \times 10^9 \frac{m^2}{kg}$$

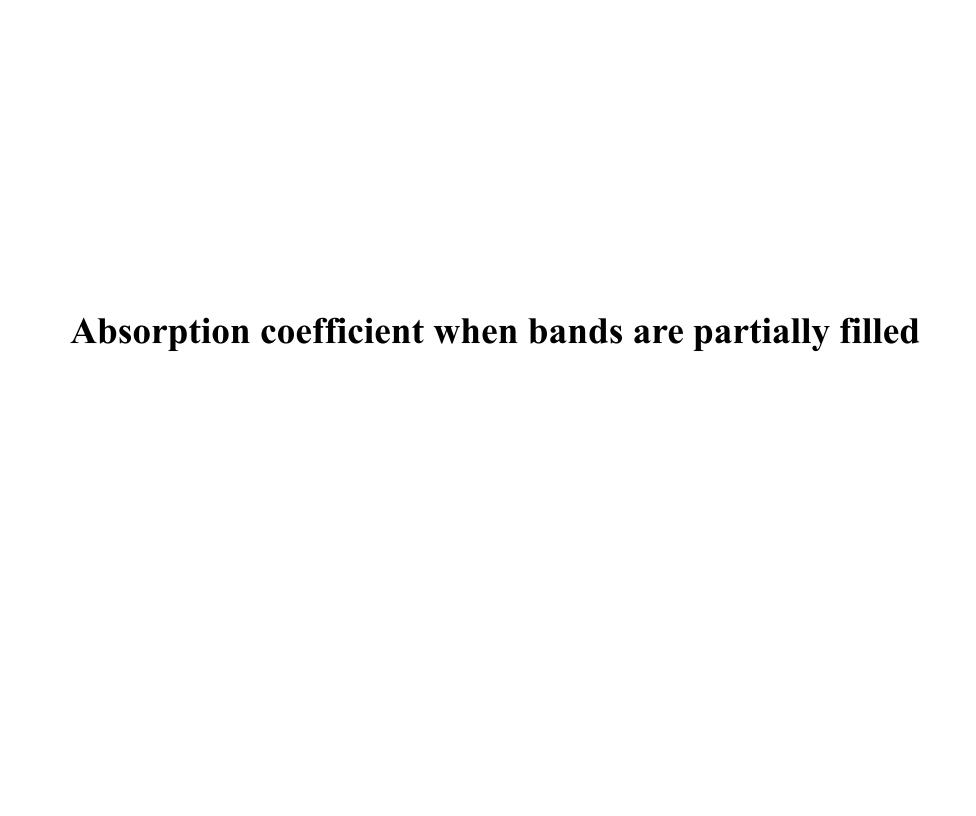
Ep :=
$$25.7eV$$
 $\frac{m0}{6} \cdot Ep = 6.243 \times 10^{-49} \text{kg} \cdot J$

$$m_r := \frac{0.067 \cdot 0.5}{0.067 + 0.5} \cdot m0$$

$$\rho r(hv) := \frac{1}{2\pi^2} \cdot \left(\frac{2 \cdot m_r}{h_bar^2}\right)^{\frac{3}{2}} \cdot \sqrt{hv - Eg} \qquad \qquad \rho r(1.43 \text{ eV}) = 6.102 \times 10^{43} \cdot \frac{1}{m^3 \cdot J}$$

$$\alpha 0(\text{hv}) := \text{C0} \cdot \frac{\text{m0}}{6} \cdot \text{Ep} \cdot \rho r(\text{hv}) \qquad \alpha 0(1.43 \, \text{eV}) = 1.845 \times 10^5 \frac{1}{\text{m}} \qquad \qquad \alpha 0(1.43 \, \text{eV}) = 1.845 \times 10^3 \frac{1}{\text{cm}}$$

Gain



CB completely full, VB completely empty, total upward transition at $\hbar\omega$:

$$R_{0}(\hbar\omega) = \frac{2}{V} \sum_{k} \left[\frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \delta(E_{b} - E_{a} - \hbar\omega) \right] = \frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \int \frac{2d\vec{k}}{(2\pi)^{3}} \delta(E_{g} + \frac{\hbar^{2}k^{2}}{2m_{r}^{*}} - \hbar\omega)$$

$$R_0(\hbar\omega) = \frac{2\pi}{\hbar} |H_{ba}|^2 \rho_r(\hbar\omega - E_g) \quad \text{unit: } [\frac{1}{m^3 s}]$$

Absorption coefficient

$$\alpha_{0}(\hbar\omega) = \frac{R(\hbar\omega)}{\text{photon flux}} = \frac{R(\hbar\omega)}{\frac{\varepsilon_{0}\varepsilon_{r}E_{0}^{2}}{2}\frac{c}{n_{r}}\frac{1}{\hbar\omega}} = \frac{R(\hbar\omega)}{\frac{\varepsilon_{0}n_{r}\omega^{2}A_{0}^{2}c}{2\hbar\omega}} \quad \text{unit: } \left[\frac{1}{m}\right]$$

$$\frac{\epsilon_0 \epsilon_r E_0}{2} \frac{c}{n_r} \frac{1}{\hbar \omega} = \frac{\epsilon_0 n_r \omega}{2\hbar \omega}$$

$$eA_0 \wedge =$$

$$H'_{ba} = -\frac{eA_0}{2m_0} \hat{e} \cdot \overrightarrow{P}_{cv}$$

$$\alpha_0(\hbar\omega) = C_0 \left| \hat{e} \cdot \vec{P}_{cv} \right|^2 \rho_r(\hbar\omega - E_g)$$

$$C_0 = \frac{\pi e^2}{n_r c \varepsilon_0 m_0^2 \omega} \approx 7 \times 10^9$$
 unit: $\left[\frac{m^2}{kg} \right]$

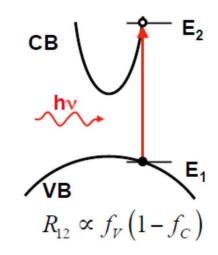
When CB and VB are partially filled:

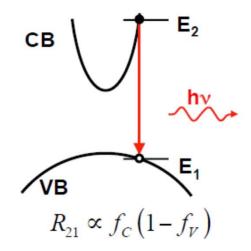
Absorption Condition: VB is occupied, CB is empty Absorption probability = $f_V(E_1)(1 - f_C(E_2))$

$$R_{12}(\hbar\omega) = \frac{2}{V} \sum_{k} \left[\frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \delta(E_{b} - E_{a} - \hbar\omega) \right] f_{V} \left(1 - f_{C} \right)$$

Emission Condition: CB is occupied, VB is empty Emission probability = $f_C(E_2)(1 - f_V(E_1))$

$$R_{21}(\hbar\omega) = \frac{2}{V} \sum_{k} \left[\frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \delta(E_{b} - E_{a} - \hbar\omega) \right] f_{C} \left(1 - f_{V} \right)$$



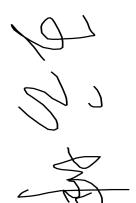


Net absorption rate:

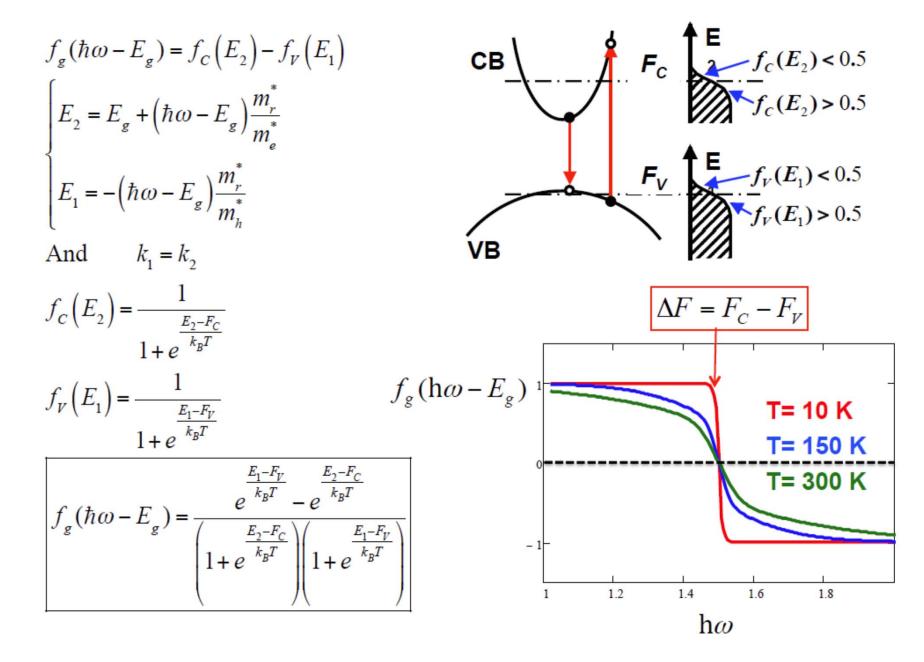
$$\begin{split} R(\hbar\omega) &= \frac{2}{V} \sum_{k} \left[\frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \delta(E_{b} - E_{a} - \hbar\omega) \right] \left[f_{V} \left(1 - f_{C} \right) - f_{C} \left(1 - f_{V} \right) \right] \\ &= \frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \int \frac{2d\vec{k}}{(2\pi)^{3}} \delta(E_{g} + \frac{\hbar^{2}k^{2}}{2m_{r}^{*}} - \hbar\omega) \left[f_{V}(k) - f_{C}(k) \right] \\ &= \frac{2\pi}{\hbar} \left| H_{ba}^{'} \right|^{2} \rho_{r} (\hbar\omega - E_{g}) \left[f_{V} \left(-\left(\hbar\omega - E_{g}\right) \frac{m_{r}^{*}}{m_{h}^{*}} \right) - f_{C} \left(E_{g} + \left(\hbar\omega - E_{g}\right) \frac{m_{r}^{*}}{m_{e}^{*}} \right) \right] \\ &\alpha(\hbar\omega) = C_{0} \left| \hat{e} \cdot \overrightarrow{P}_{cv} \right|^{2} \rho_{r} (\hbar\omega - E_{g}) \left[-f_{g} (\hbar\omega - E_{g}) \right] \end{split}$$

Fermi Inversion Factor:

$$f_g(\hbar\omega - E_g) = f_C \left(E_g + \left(\hbar\omega - E_g \right) \frac{m_r^*}{m_e^*} \right) - f_V \left(-\left(\hbar\omega - E_g \right) \frac{m_r^*}{m_h^*} \right)$$



Fermi Inversion Factor



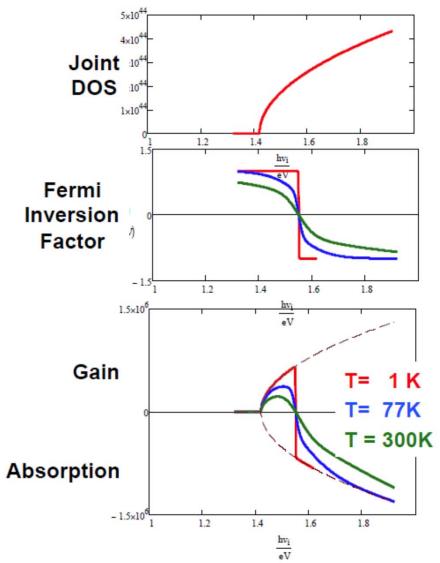
Optical Gain Coefficient

$$\alpha_0(\hbar\omega) = C_0 \left| \hat{e} \cdot \vec{P}_{cv} \right|^2 \rho_r(\hbar\omega - E_g)$$

$$\alpha(\hbar\omega) = \alpha_0(\hbar\omega) \Big[-f_g(\hbar\omega - E_g) \Big]$$

$$g(\hbar\omega) = -\alpha(\hbar\omega)$$

$$g(\hbar\omega) = \alpha_0(\hbar\omega) f_g(\hbar\omega - E_g)$$



Joint Density of States for Semiconductor

The electron states associated with optical transition r r r are related by conservation of mementum: $k_b \approx k_a \approx k$

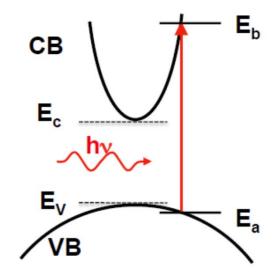
$$E_b = E_C + \frac{\bar{h}^2 k^2}{2m_e^*}$$
 $E_a = E_V - \frac{\bar{h}^2 k^2}{2m_h^*}$

$$E_b - E_a = (E_C - E_V) + \frac{\hbar^2 k^2}{2} \left(\frac{1}{m_e^*} + \frac{1}{m_h^*} \right)$$

$$h\omega = E_g + \frac{\hbar^2 k^2}{2m_r^*}$$

Joint density of states for the pair of electron states:

$$\rho_r(\hbar\omega - E_g) = \frac{1}{2\pi^2} \left(\frac{2m_r^*}{\hbar^2}\right)^{3/2} \sqrt{\hbar\omega - E_g}$$



Optical Gain Coefficient versus Bias

$$g(\mathrm{h}\omega) = \alpha_{\scriptscriptstyle 0}(\mathrm{h}\omega) f_{\scriptscriptstyle g}(\mathrm{h}\omega - E_{\scriptscriptstyle g})$$

Bernard-Duraffourg Inversion Condition

$$\Delta F = F_C - F_V > E_g$$

Spectral Range of Gain

$$E_g < h\omega < \Delta F = F_C - F_V$$

